

# COMPOUND FIELD EFFECT POWER TRANSISTOR $\mu$ PA1603

## **MONOLITHIC POWER MOS FET ARRAY**

#### **DESCRIPTION**

The  $\mu$ PA1603 is Monolithic N-channel Power MOS FET Array that built in 4 circuits, Clump Diode and resistances designed for LED, Relay, Thermal Head, and so on.

#### **FEATURES**

- Direct driving is possible by standard Logic IC or Microcomputer.
  (4 V driving is possible)
- Output Voltage: Vo(peak) = 50 V MAX.
  Output Current: Io(peak) = 1.5 A MAX.
- Ron = 1  $\Omega$  TYP. at: lo = 600 mA, Vi = 4 V
- Wide Operation Temperature: -40 to +85 °C
- Output Voltage Clump Diode built in.

#### ORDERING INFORMATION

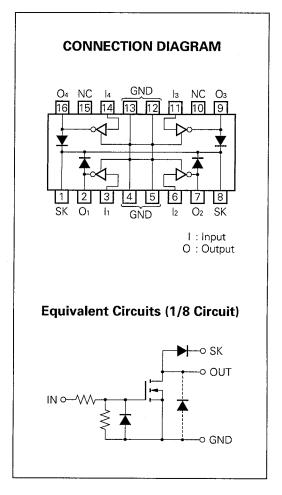
Part Number	Package	Quality Grade
μPA1603CX	16-Pin DIP	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Output Voltage	Vo(DC)	30	V
Output Peak Voltage*	VO(peak)	50	V
Input Voltage	Vı	-0.5 to +20	V
Output Current (DC)	lo(DC)	870	mA/unit
Output Current (pulse)**	lO(pulse)	1500	mA/unit
Input Current	Ī1	±10	mA/unit
Diode Reverse Voltage	VR	50	V
Diode Forward Current	lF	1500	mA/unit
Total Power Dissipation	Po	1.0	W/PKG
Operating Temperature	Topt	-40 to +85	°C
Storage Temperature	$T_{stg}$	-55 to +150	°C

- \* PW ≦ 10 ms, Duty Cycle ≦ 50 %
- \*\* PW ≦ 10 ms, Duty Cycle ≦ 30 %





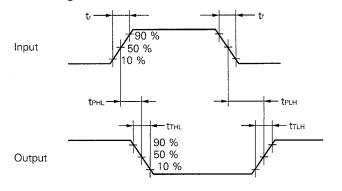
## RECOMMENDED OPERATING CONDITIONS (Ta = -40 to +85 °C)

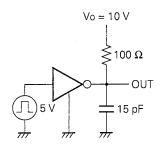
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	Vo(DC)			28	V	
	lo(DC)			540	mA/unit	DC, 1 circuit
Output Current	IO(pulse)			600	mA/unit	PW ≦ 10 ms, Duty Cycle ≦ 20 %, 4 circuits
Input Voltage	Vı	0		15	V	
High-Level Input Voltage	Vih	2			V	
Low-Level Input Voltage	VıL			0.8	V	
Diode Reverse Voltage	Vr			40	V	
Diode Forward Current	<b>I</b> F			600	mA	

## **ELECTRICAL CHARACTERISTICS (Ta = 25 °C)**

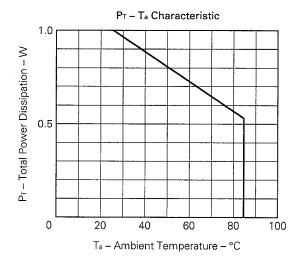
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Output Leakage Current	lo(OFF)			10	μΑ	VI = 0, Vo = 50 V	
Output On-state Resistance	Ron		1	1.3	Ω	V <sub>I</sub> = 4 V, I <sub>O</sub> = 600 mA	
0	V0(0N)1			0.1	V	Vı = 5 V, lo = 10 mA	
Output On-state Voltage	V0(0N)2			1.0	V	Vi = 5 V, lo = 600 mA	
	Vi(OFF)			0.8	V	Vo = 50 V, Io = 100 μA	
Input Voltage	V1(0N)1	2			V	Vo = 0.8 V, lo = 1 mA	
	VI(ON)2	4			V	Vo = 0.8 V, Io = 600 mA	
Lawrence Community	Пін			2	mA	VI = 20 V, Vo = 0 V	
Input Current	lıı			-1	μΑ	VI = 0 V, Vo = 50 V	
Input Capacitance	Ciss		80		pF	V <sub>I</sub> = 0 V	
Output Capacitance	Coss	.,	100		pF	Vo = 10 V	
Reverse Transfer Capacitance	Crss		40		pF	f = 1 MHz	
Dalay Time	<b>TPHL</b>		20		ns	Vo = 10 V, Rι = 100 Ω	
Delay Time	<b>t</b> PLH	•	70		ns	C <sub>L</sub> = 15 pF	
Rise Time	tтьн		50		ns	tr, tr ≦ 5 ns See Fig. 1	
Fall Time	tтнь		30		ns		
Diada Laskaga Current	l-			50	μΑ	V <sub>R</sub> = 50 V, T <sub>a</sub> = 25 °C	
Diode Leakage Current	l <sub>R</sub>			100	μΑ	V <sub>R</sub> = 50 V, T <sub>a</sub> = 85 °C	
Diode Forward Voltage	VF			2	٧	I <sub>F</sub> = 1.25 A	

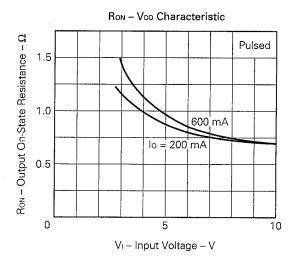
Fig. 1 Switching Wave Forms and Test Circuits

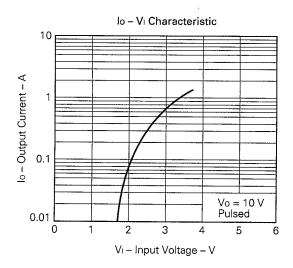


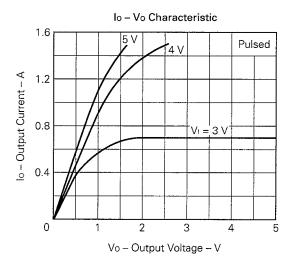


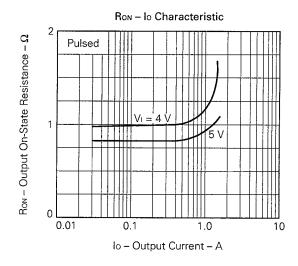
## TYPICAL CHARACTERISTICS (Ta = 25 °C)

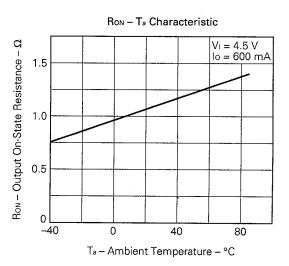


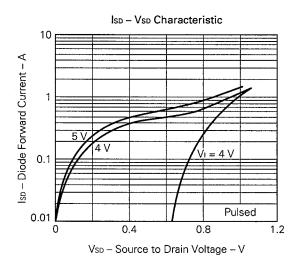


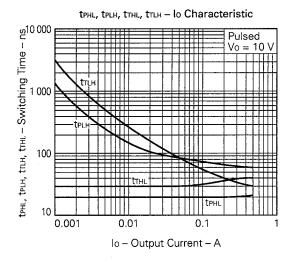








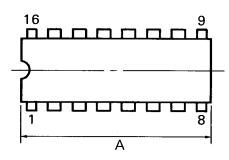


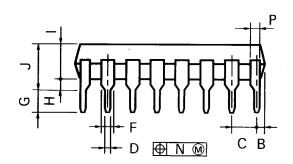


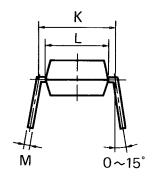
## **PACKAGE DIMENSIONS**

## • μPA1603CX

# 16PIN PLASTIC DIP (300 mil)







P16C-100-300A,C

## **NOTES**

- Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
Α	20.32 MAX.	0.800 MAX.
В	1.27 MAX.	0.050 MAX.
С	2.54 (T.P.)	0.100 (T.P.)
D	0.50 <sup>±0.10</sup>	0.020 + 0.004
F	1.2 MIN.	0.047 MIN.
G	3.5 <sup>±0.3</sup>	0.138 ±0.012
Н	0.51 MIN.	0.020 MIN.
	4.31 MAX.	0.170 MAX.
_ J	5.08 MAX.	0.200 MAX.
К	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
М	0.25 - 0.05	0.010 - 0.004
N	0.25	0.01
Р	1.0 MIN.	0.039 MIN.



## **RECOMMENDED SOLDERING CONDITIONS**

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

#### TYPES OF THROUGH HOLE MOUNT DEVICE

#### $\mu$ PA1603CX

Soldering process	Soldering conditions	Symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	

#### Reference

Document name	Document No.
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207
Semiconductor device package manual	IEI-1213
SMD surface mount technology manual	IEI-1207

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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

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